

# FR16B02 thru FR16JR02

## Silicon Fast Recovery Diode

 $V_{RRM} = 100 \text{ V} - 600 \text{ V}$   $I_F = 16 \text{ A}$ 

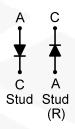
**DO-4 Package** 

#### **Features**

- High Surge Capability
- $\bullet$  Types from 100 V to 600 V  $V_{\text{RRM}}$
- Not ESD Sensitive

#### Note:

- 1. Standard polarity: Stud is cathode.
- 2. Reverse polarity (R): Stud is anode.
- 3. Stud is base.







### Maximum ratings, at T<sub>i</sub> = 25 °C, unless otherwise specified ("R" devices have leads reversed)

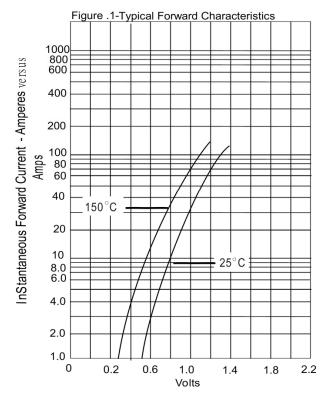
Symbol	Conditions	FR16B(R)02	FR16D(R)02	FR16G(R)02	FR16J(R)02	Unit
$V_{RRM}$		100	200	400	600	V
V <sub>RMS</sub>		70	140	280	420	V
$V_{DC}$		100	200	400	600	V
ent I <sub>F</sub>	T <sub>C</sub> ≤ 100 °C	16	16	16	16	Α
ward I <sub>F,SM</sub>	$T_C = 25 ^{\circ}\text{C},  t_p = 8.3 \text{ms}$	225	225	225	225	Α
Tj		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C
T <sub>stg</sub>		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C
	$V_{RRM}$ $V_{RMS}$ $V_{DC}$ ent $I_F$ ward $I_{F,SM}$	$V_{RRM}$ $V_{RMS}$ $V_{DC}$ ent $I_F$ $T_C \le 100 ^{\circ}C$ ward $I_{F,SM}$ $T_C = 25 ^{\circ}C$ , $t_p = 8.3 ^{o}ms$	$V_{RRM}$ 100 $V_{RMS}$ 70 $V_{DC}$ 100  ent $I_F$ $T_C \le 100 ^{\circ}\text{C}$ 16  ward $I_{F,SM}$ $T_C = 25 ^{\circ}\text{C}$ , $t_p = 8.3 \text{ms}$ 225 $T_j$ -55 to 150	$V_{RRM}$ 100     200 $V_{RMS}$ 70     140 $V_{DC}$ 100     200       ent $I_F$ $T_C \le 100 ^{\circ}\text{C}$ 16     16       ward $I_{F,SM}$ $T_C = 25 ^{\circ}\text{C}$ , $t_p = 8.3 \text{ms}$ 225     225 $T_J$ -55 to 150     -55 to 150	$V_{RRM}$ 100     200     400 $V_{RMS}$ 70     140     280 $V_{DC}$ 100     200     400       ent $I_F$ $T_C \le 100 ^{\circ}$ C     16     16     16       ward $I_{F,SM}$ $T_C = 25 ^{\circ}$ C, $t_p = 8.3  \text{ms}$ 225     225     225	$V_{RRM}$ 100       200       400       600 $V_{RMS}$ 70       140       280       420 $V_{DC}$ 100       200       400       600         ent $I_F$ $T_C \le 100 ^{\circ}$ C       16       16       16       16         ward $I_{F,SM}$ $T_C = 25 ^{\circ}$ C, $t_p = 8.3 \text{ms}$ 225       225       225       225

#### Electrical characteristics, at Tj = 25 °C, unless otherwise specified

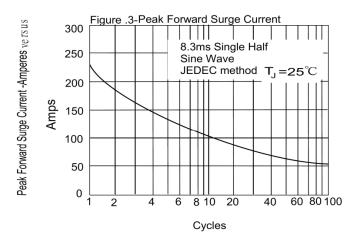
Parameter	Symbol	Conditions	FR16B(R)02	FR16D(R)02	FR16G(R)02	FR16J(R)02	Unit
Diode forward voltage	$V_{F}$	I <sub>F</sub> = 16 A, T <sub>j</sub> = 25 °C	0.9	0.9	0.9	0.9	V
Reverse current	I <sub>R</sub>	V <sub>R</sub> = 100 V, T <sub>j</sub> = 25 °C	25	25	25	25	μA
		$V_R = 100 \text{ V}, T_j = 150 ^{\circ}\text{C}$	6	6	6	6	mA
Recovery Time							
Maximum reverse recovery time	T <sub>RR</sub>	I <sub>F</sub> =0.5 A, I <sub>R</sub> =1.0 A, I <sub>RR</sub> = 0.25 A	200	200	200	250	nS
Thermal characteristics							
Thermal resistance, junction - case	$R_{thJC}$		1.5	1.5	1.5	1.5	°C/W



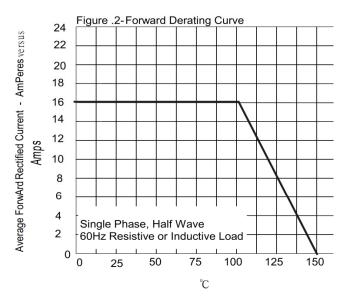
## FR16B02 thru FR16JR02



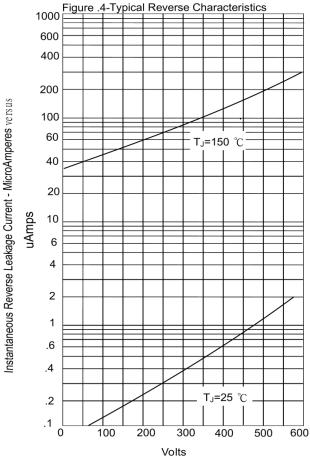
Instantaneous Forward Voltage - Volts



Number Of Cycles At 60Hz - Cycles



Case Temperature -  $^{\circ}$ C

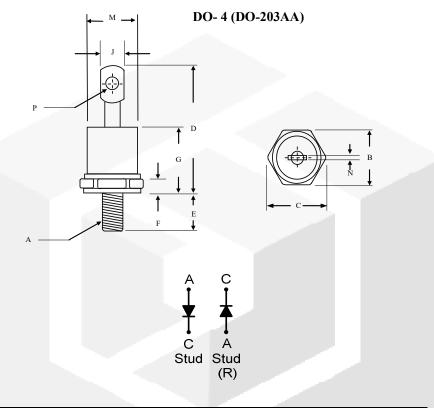


Percent Of Rated Peak Reverse Voltage - Volts



### Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



	Inc	hes	Millimeters		
	Min	Max	Min	Max	
A		10-32	UNF		
В	0.424	0.437	10.77	11.10	
С		0.505		12.82	
D		0.800		20.30	
Е	0.453	0.492	11.50	12.50	
F	0.114	0.140	2.90	3.50	
G		0.405		10.29	
J		0.216		5.50	
M		φ0.302		φ7.68	
N	0.031	0.045	0.80	1.15	
P	0.070	0.79	1.80	2.00	